

# Schottky Diode

## **PBYR1060**

60V / 10A

# DATASHEET

OEM – Philips

Source: Philips Databook 1999

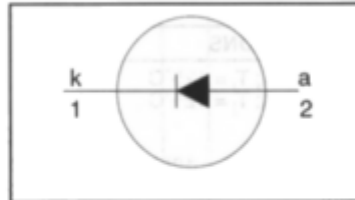
## Rectifier diodes Schottky barrier

## PBYR10100 series

### FEATURES

- Low forward volt drop
- Fast switching
- Reverse surge capability
- High thermal cycling performance
- Low thermal resistance

### SYMBOL



### QUICK REFERENCE DATA

$$V_R = 60 \text{ V} / 80 \text{ V} / 100 \text{ V}$$

$$I_{F(AV)} = 10 \text{ A}$$

$$V_F \leq 0.7 \text{ V}$$

### GENERAL DESCRIPTION

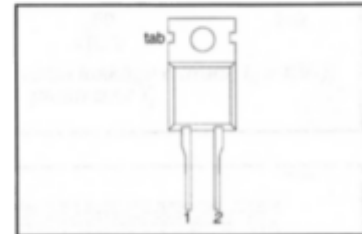
Schottky rectifier diodes in a plastic envelope. Intended for use as output rectifiers in low voltage, high frequency switched mode power supplies.

The PBYR10100 series is supplied in the conventional leaded SOD59 (TO220AC) package.

### PINNING

PIN	DESCRIPTION
1	cathode
2	anode
tab	cathode

### SOD59 (TO220AC)



### LIMITING VALUES

Limiting values in accordance with the Absolute Maximum System (IEC 134)

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.			UNIT
				60	80	100	
		<b>PBYR10</b>					
$V_{RRM}$	Peak repetitive reverse voltage		-	60	80	100	V
$V_{RWM}$	Working peak reverse voltage		-	60	80	100	V
$V_R$	Continuous reverse voltage	$T_{mb} \leq 139 \text{ }^\circ\text{C}$	-	60	80	100	V
$I_{F(AV)}$	Average rectified forward current	square wave; $\delta = 0.5$ ; $T_{mb} \leq 133 \text{ }^\circ\text{C}$	-	10			A
$I_{FRM}$	Repetitive peak forward current	square wave; $\delta = 0.5$ ; $T_{mb} \leq 133 \text{ }^\circ\text{C}$	-	20			A
$I_{FSM}$	Non-repetitive peak forward current	$t = 10 \text{ ms}$	-	135			A
		$t = 8.3 \text{ ms}$ sinusoidal; $T_j = 125 \text{ }^\circ\text{C}$ prior to surge; with reapplied $V_{RRM(max)}$ pulse width and repetition rate limited by $T_{jmax}$	-	150			A
$I_{VRM}$	Peak repetitive reverse surge current		-	1			A
$T_j$	Operating junction temperature		-	150			$^\circ\text{C}$
$T_{stg}$	Storage temperature		-65	175			$^\circ\text{C}$

### THERMAL RESISTANCES

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$R_{th(j-mb)}$	Thermal resistance junction to mounting base		-	-	2	K/W
$R_{th(j-a)}$	Thermal resistance junction to ambient	in free air	-	60	-	K/W

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**ELECTRICAL CHARACTERISTICS** $T_j = 25\text{ }^\circ\text{C}$  unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
$V_F$	Forward voltage	$I_F = 10\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.61	0.7	V
		$I_F = 20\text{ A}; T_j = 125\text{ }^\circ\text{C}$	-	0.74	0.85	V
		$I_F = 20\text{ A}$	-	0.88	0.95	V
$I_R$	Reverse current	$V_R = V_{RWM}$	-	5	150	$\mu\text{A}$
		$V_R = V_{RWM}; T_j = 125\text{ }^\circ\text{C}$	-	5	15	mA
$C_j$	Junction capacitance	$V_R = 5\text{ V}; f = 1\text{ MHz}; T_j = 25\text{ }^\circ\text{C to } 125\text{ }^\circ\text{C}$	-	420	-	pF

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